

P-Channel -20V (D-S) Power MOSFET

Features

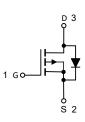
- 100% Avalanche Tested
- Halogen Free, Pb-Free
- RoHS Compliant

Applications

- Relay driver
- Switching circuits
- High-side load switch
- High-speed line driver

° C	
	2
V	^





Absolute Maximum Ratings (T _A =25°C unless otherwise noted)							
Parameter	Symbol	Value	Unit				
Drain Source Voltage	V _{DS}	V _{DS} -20					
Gate Source Voltage	V_{GS}	V _{GS} ±20					
Drain Current, Continuous V _{GS} =-10V	Tc=25°C	lo	-2	А			
Drain Current, Pulsed (Note 1)	lом	-6	А				
Power Dissipation	er Dissipation Tc=25°C		1.3	W			
Operating Junction/ Storage Temperat	TJ/ Tstg	-55 to +150	°C				

Note 1: Single pulse; $t_p \leq 1us$.

Thermal Characteristics								
Parameter	Symbol	Мах	Unit					
Thermal Resistance Junction to Ambient (Note 2)	R _{thJA}	100	°C/W					

Note 2: Device mounted on 1 square inch FR4 PCB board, with 2oz single-sided copper, in a 25°C still air environment.



Electrical Characteristics (T _A =25°C unless otherwise noted)						
Parameter	Symbol	Symbol Test Conditions		Тур	Max	Unit
Drain Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =-250µA	-20			V
Zero Gate Voltage Drain Current	IDSS	V _{DS} =-20V, V _{GS} =0V			-1	uA
Gate Threshold Voltage	V _{GS(TH)}	V _{DS} =V _{GS} , I _{DS} =-250uA	-0.4		-1	V
Gate Leakage Current	I _{GSS}	V_{GS} =±12V, V_{DS} =0V			±100	nA
Drain-Source On-state	D	V _{GS} =-4.5V, I _D =-2A		126	155	mΩ
Resistance (Note 3)	R _{DS(on)}	V _{GS} =-2.5V, I _D =-1A		166	210	
Total Gate Charge	Qg			9.4		nC
Gate-Source Charge	Q _{gs}	V _{GS(off)} =0V, V _{GS(on)} =-4.5V, V _{DD} =-10V, I _D =-3A		0.9		
Gate-Drain Charge	Q_{gd}			2.4		
Turn-on Delay Time	t _{d(on)}			5		
Turn-on Rise Time	tr	V _{GS} =-4.5V, V _{DD} =-20V,		14		
Turn-off Delay Time	$t_{d(off)}$	$R_L=10\Omega, R_G=3\Omega$		12		ns
Turn-off Fall Time	t _f			2.9		
Input Capacitance	Ciss			171		
Output Capacitance	Coss	V _{GS=} 0V, V _{DS} =-20V, f=100KHz		25		pF
Reverse Transfer Capacitance	Crss			19		

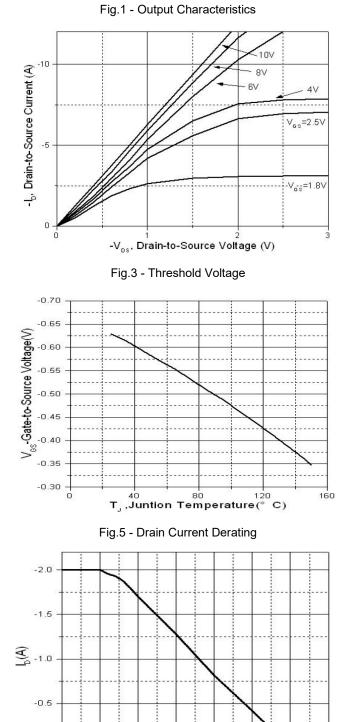
Reverse Diode Characteristics (T _A =25°C unless otherwise noted)						
Parameter	Symbol Test Conditions		Min.	Тур.	Max.	Unit
Forward Current, Continuous	I _{SD}	I _{SD} T _C =25°C			-2	А
Diode Forward Voltage (Note 3)	Vsd	I _F =-1A, V _{GS} =0V			1.2	V

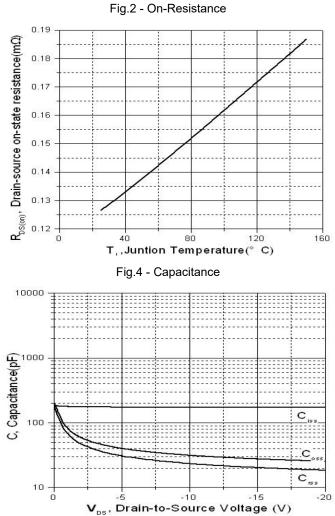
Note 3: Pulse test; pulse width \leq 380µs, duty cycle \leq 1%.



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Typical Characteristics Curves (T_A = 25°C unless otherwise noted)





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0.0 +

25

50

75

T_c(° C)

100

125

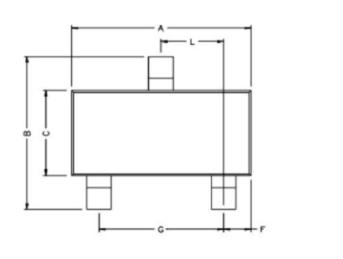
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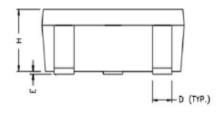
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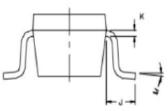


Package Outline Dimensions (Unit: millimeters)

SOT-23



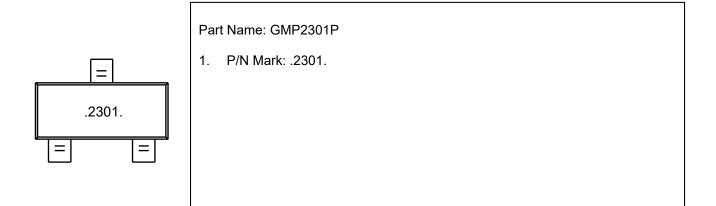




REF.	Milli	meter	REF.	Millimete		
NEF.	Min.	Max.	KEF.	Min.	Max.	
Α	2.80	3.00	G 1.80		2.00	
В	2.30	2.50	Н	0.90	1.1	
С	1.20	1.40	K	0.10	0.20	
D	0.30	0.50	J	0.35	0.70	
E	0	0.10	L	0.92	0.98	
F	0.45	0.55	М	0°	10°	



Marking Outline





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